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# Contents

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## Research Articles

<b>A Review of Concept of Force Measurements between the Past and Today</b> <i>Ebtisam H. Hasan</i> .....	1
<b>Design, Development and Testing of a Semicircular Type Capacitive Angular Position Sensor</b> <i>Nikhil Gaurav, Sagarika Pal</i> .....	16
<b>Design, Development and Calibration of a Portable Capacitive Moisture Meter</b> <i>Mahmoud Soltani, Reza Alimardani</i> .....	24
<b>Laser Power Measurement Using Commercial MEMS Pressure Sensor along with PSoC Embedded Read-out</b> <i>J. Jayapandian and K. Prabakar</i> .....	33
<b>Design and Development of Embedded System for the Measurement of Thermal Conductivity of Liquids by Transient Hot Wire Method</b> <i>Nagamani Gosala, Raghavendra Rao Kanchi</i> .....	42
<b>Performance Assessment of PCA, MF and SVD Methods for Denoising in Chemical Sensor Array Based Electronic Nose System</b> <i>S. K. Jha and R. D. S. Yadava</i> .....	57
<b>Simple Design of a PID Controller and Tuning of Its Parameters Using LabVIEW Software</b> <i>Subrata Chattopadhyay, Ganesh Roy and Mrutyunjaya Panda</i> .....	69
<b>The DC Motor Speed Controller Using AT89S52 Microcontroller to rotate Stepper Motor attached into Potentiometer in Variable Regulated Power Supply</b> <i>Marhaposan Situmorang</i> .....	86
<b>Use of Polythiophene as a Temperature Sensor</b> <i>D. S. Kelkar, A. B. Chourasia, V. Balasubramanian</i> .....	97
<b>Modeling of a Non-invasive Electromagnetic Sensor for the Measurement Glycaemia</b> <i>A. Rouane, D. Kourtiche, S. M. Alavi</i> .....	105
<b>CdO Doped Indium Oxide Thick Film as a Low Temperature H<sub>2</sub>S Gas Sensor</b> <i>D. N. Chavan, V. B. Gaikwad, Ganesh E. Patil, D. D. Kajale, G. H. Jain</i> .....	122
<b>Design and Simulation of Double-spiral Shape Micro-heater for Gas Sensing Applications</b> <i>Mahanth Prasad, R. P. Yadav, V. Sahula and V. K. Khanna</i> .....	115
<b>Glucose Concentration Sensor Based on Long Period Grating Fabricated from Hydrogen Loaded Photosensitive Fiber</b> <i>T. M. Libish, J. Linesh, M. C. Bobby, B. Nithyaja, 1S. Mathew, C. Pradeep and P. Radhakrishnan</i> .....	142



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## Modeling of a Non-invasive Electromagnetic Sensor for the Measurement Glycaemia

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**Abstract:** In this paper, we present the modeling of a non-invasive electromagnetic sensor for the measurement glycaemia. The model is based on a bio-impedance measurement. First, we optimized the dimensions of the sensor's parameters that can influence on measurement. Second, we investigated the influence of the dielectric parameters on the conductivity and its impact on the measurement of glycaemia. Results from this study demonstrate that the variation of the sensor impedance depends on the resistance and the inductance, which depend on the conductivity. The sensitivity of the output and input signal ratio strongly depends on the conductivity of the medium under investigation. Maximum conductivity at the resonance frequency was demonstrated. *Copyright © 2011 IFSA.*

**Keywords:** Electromagnetic sensor, Electric model sensor, Conductivity, Bio-impedance measurement, Measure, Glycaemia.

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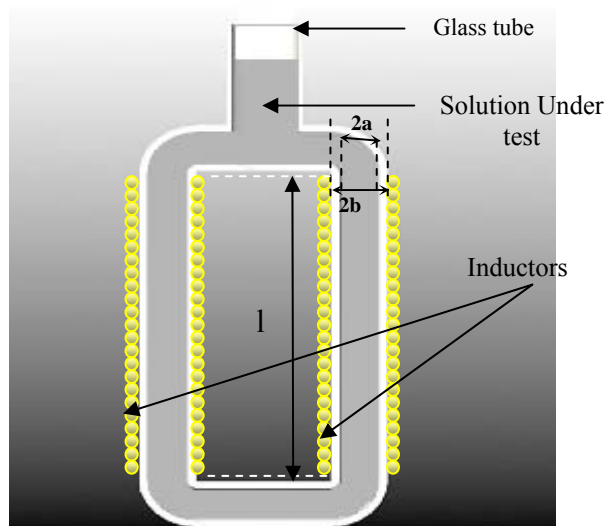
### 1. Introduction

Diabetes is one the most debilitating health problems in the world. The main problem of diabetes is the chronic effect of glycaemia which leads to cardiovascular diseases, diabetic neuropathy and organs failure. These complications could progress and worsen when the glycaemia is not controlled or balanced accordingly. However, frequent control and management of the glycaemia has been shown to greatly reduce the number of diabetes complications [1, 2]. Diabetic patients are required to frequently check the level of their blood glucose to avoid the secondary effects of the diabetes. Blood glucose levels are monitored daily through skin prick method, which is executed several times during the day to avoid an imbalance of blood glucose level. The prick of the skin which is painful and aversive event

discourages many patients to adhere to an appropriate control of their blood glucose levels, which could lead to higher risks of diabetes complications. In order to improve the quality of life of the diabetic patients a non-invasive glucose level monitoring remains the most attractive approach for diabetic patients. A non-invasive approach will allow more frequent measurements of blood glucose without the painful sensation endured during skin prick. Several research studies have focused on developing a non-invasive method to help control glycaemia [3-6]. In the current study, we have developed an original method for a non-invasive measurement of glycaemia which is based on an electromagnetic sensor [7]. This paper focuses on the modeling of this non-invasive sensor which measures the glycaemia. This modeling is based on bio-impedance measurement [8-11]. The purpose of this study is to optimize the sensor characteristics that could influence glucose measurements. The theoretical study demonstrates that the variation of the sensor impedance, such as resistance  $R$  and inductance  $L$ , as a function of the conductivity is an important step to achieve to achieve high sensitivity.

## 2. Materials and Methods

The sensor consists of two induction coils coupled by a blood environment representing the solution under investigation as shown in Fig. 1. The glass tube, as an insulator, contains this solution is between the inductors and this medium. The induction wire is coiled around a 1 mm diameter glass tube. By neglecting the radius of the wire, the induction diameter is close to that of the glass tube. The length and the diameter of the inductor are 80 mm and 20 mm, respectively. The distance between the two axes of the two inductors is 40 mm. Thus, two distinct spaces are defined within inside the inductors. The first space consists of the solution under test, which can be considered as a conductor. Whereas the second space represents the hull of the glass tube which is considered as an insulator (its resistivity is  $\rho \approx 2 * 10^{13}$  ohm \* m).



**Fig. 1.** Schema of the test-cell geometry.

### 2.1. Principle of the Sensor

We have considered a differential method for the non-invasive measurement of the glycaemia using two dimensionally identical sensors. One of the sensors allows compensation for the temperature effect. A function generator provides an input signal  $V_i$  at the resonance frequency which is applied to the first inductor of each sensor. Two outputs signal  $V_o$  and  $V'_o$  are collected on the second inductors

of the two sensors. These ratios  $V_o/V_I$ ,  $V'_o/V_I$ , and the difference  $(V_o/V_I - V'_o/V_I)$  are calculated using an electronic card developed in our laboratory. A detailed description of the procedure is given in [7]. In this paper, we are interested in optimizing the dimension of the sensor by calculating its impedance, and studying the influence of each parameter on the sensor.

## 2.2. Calculation of the Magnetic Field

Under these conditions, the magnetic field  $H$  behaves practically as an inductance in vacuum. The magnetic field  $H$  is calculated by the following equation:

$$H = \frac{nI}{\ell}, \quad (1)$$

where:

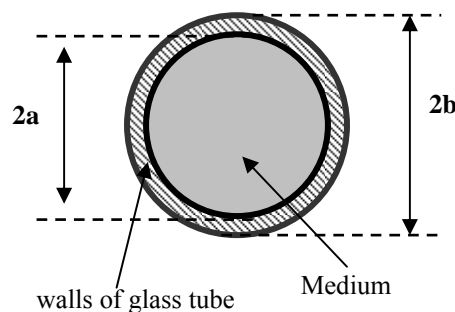
$l$  = length of the inductor;

$n$  = number of the spire;

$I$  = current in the inductor;

$H$  = magnetic field.

Assuming that  $\ell \gg b$ , Fig. (1, b) represents the external diameter of the inductor, Fig. 2, and in a conductor medium, the magnetic field  $H$  should to be homogeneous at all point belonging to any straight line parallel to  $Z$  axis, Fig. 3. The magnetic field  $H$  has only one component  $H_z$  when the field lines are parallel to  $Z$ -axis in the medium. The amplitude of the field, at any point  $M$  inside this medium depends only on the distance between this point  $M$  and the  $Z$ -axis.  $H(r)$  represents the field  $H$  inside the medium. Based on the geometry of the inductors-medium system, we choose cylindrical coordinates. The sample under test (salted water, blood, or gelatin) is a non-magnetic material suggesting that the susceptibility ( $\chi_m$ ) does not depend on the field  $H$ .



**Fig. 2.** Cross-section of the cell showing the medium and the walls of glass tube.

Consequently, the permeability is independent of the field  $H$ . The electromotive force  $E$  in the borders of the reel, Fig. 4, is given by:

$$E = j n \omega \Phi_R = V - R_0 I = (Z - R_0) I \quad (2)$$

$$= (R - R_0) I + j L \omega I \quad (3)$$

$\Phi_R$ : Resulting magnetic flux when the inductor is charged,  $\omega$ : pulsation

$V$ : Voltage at the terminals of the inductor charged by the middle.



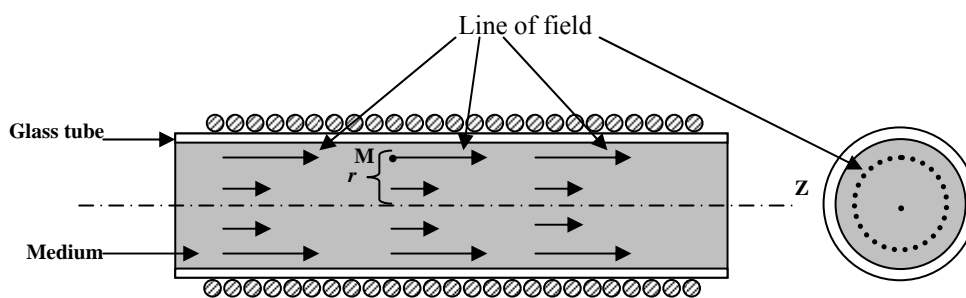


Fig. 3. Lines of magnetic field H inside the reel.

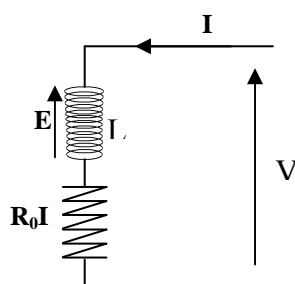


Fig. 4. Electric model of the reel.

Where

$$Z = R + jL \omega , \quad (4)$$

impedance of the inductor charged by the middle, and  $R_0$  is the resistance of the reel in vacuum.

Therefore:

$$\Phi_R = \frac{j(R - R_0)I}{n\omega} + \frac{L I}{n} \quad (5)$$

These previous relations show that we need to determine the magnetic flux, which crosses it in order to determine its impedance  $Z$ . The magnetic flux is defined by:

$$\Phi = \int_{\mu} \vec{H}(\vec{r}) \cdot \vec{r} \, d\vec{r} \quad (6)$$

The magnetic field  $H(r)$  can be deduced from Laplace's law:

$$\Delta \vec{H} = - \overrightarrow{curl \, curl} \, \vec{H} \quad (7)$$

Since the field  $H$  in the medium depends only on the component  $r$ , we obtain the following differential equation

$$\frac{\partial^2 H(r)}{\partial r^2} + \frac{1}{r} \frac{\partial H(r)}{\partial r} - \sigma j \mu \omega H(r) = 0 \quad (8)$$

The general solution of this equation is obtained by using Bessel's functions; details of the resolution of this equation are found in [12].

$$H(r) = nI \frac{M_0(kr)}{\ell M_0(ka)} \exp(j(\theta_0(kr) - \theta_0(ka))) \quad (9)$$

$M_0$  and  $\theta_0$  are the amplitude and the phase of Bessel's function of first species at order 0.  $n$ ,  $I$ ,  $\ell$ , are defined above.  $a$  is the internal radius of the glass tube, Fig. 3.

The above expression of the magnetic field shows that:

- When  $r$  is close to zero (on Z-axis), then the magnetic field  $H$  becomes:

$$H(0) = nI \frac{1}{\ell M_0(ka)} \quad (10)$$

- When  $r$  is close to  $a$ , then the magnetic field  $H$  becomes:

$$H(r) = \frac{nI}{\ell} \quad (1)$$

If we attribute:

$$k^2 = \sigma \mu \omega, \quad (11)$$

then it is very useful to note that  $k$  is proportional to the permeability ( $\mu$ ), the pulsation ( $\omega$ ) and the conductivity ( $\sigma$ ) of the medium.

### 2.3. Calculation of Resulting Magnetic Flux ( $\Phi_R$ ) and the Impedance $Z$

The assumption ( $\ell \gg b$ ) enables us to consider that the magnetic flux across all the whorls of solenoid are constant.

#### 2.3.1. Calculation of Flux $\Phi_m$

The flux  $\Phi_m$  represents the magnetic flux across the medium under investigation. The magnetic flux across a surface  $S$ , of a medium exposed to a magnetic field  $H(r)$ , depends only on the distance  $r$  between this point and Z-axis on the solenoid (Fig. 2). In this case:

$$\Phi_m = \int_0^a 2\pi \mu r H(r) dr, \quad (12)$$

where  $a$  is the radius of the medium under test.

$$\Phi_m = -j \frac{\mu 2\pi n I a}{\ell M_0(ka) k} M_1(ka) \exp\left[\theta_1(ka) - \theta_0(ka) - \frac{\pi}{4}\right] \quad (13)$$

$M_1$  and  $\theta_1$  are the amplitude and the phase of Bessel's function of first species at order 1.  $M_0$  and  $\theta_0$  are the amplitude and the phase of Bessel's function of first species at order 0.

### 2.3.2. Calculation of the Magnetic Flux $\Phi_v$ across the Walls of the Tube

The second component  $\Phi_v$  denotes the magnetic flux inside the walls of the glass tube. The magnetic field in the walls of the glass tube is homogeneous, and is equal to:

$$H = \frac{nI}{\ell} \quad (1)$$

The surface ( $S_1$ ) through which the flux  $\Phi_v$  flow as shown in Fig. (3), is given by:

$$S_1 = \pi (b^2 - a^2) \quad (14)$$

Thus, the flux ( $\Phi_v$ ) is obtained by the integral of the magnetic field  $H(r) = \frac{nI}{\ell}$  (1) across all the surface ( $S_1$ ) is:

$$\Phi_v = \int_0^{2\pi} \int_a^b \mu' \frac{nI}{\ell} r \, dr \, d\theta = \frac{\pi \mu' n I}{\ell} (b^2 - a^2), \quad (15)$$

where  $\mu'$  is the permeability of the walls of the glass tube  $a$  and  $b$  are the internal and external radius, respectively, of the glass tube, Fig. 3.

### 2.3.3. Calculation of the Resulting Magnetic Flux $\Phi_R$

The resulting magnetic flux ( $\Phi_R$ ) is calculated by:

$$\Phi_R = \Phi_v + \Phi_m = \frac{\pi \mu' n I}{\ell} (b^2 - a^2) - j \frac{\mu 2\pi n I a}{\ell M_0(ka) k} M_1(ka) \exp\left[\theta_1(ka) - \theta_0(ka) - \frac{\pi}{4}\right] \quad (16)$$

Thus, the identification of equations (5) and (16), allows obtaining the expressions of (R) and (L) that representing the impedance of the inductors, by the following equations:

$$R = R_0 - \frac{\mu 2\pi n^2 \omega}{\ell M_0(ka)} \frac{a}{k} M_1(ka) \cos\left(\theta_1(ka) - \theta_0(ka) - \frac{\pi}{4}\right) \quad (17)$$

$$L = \frac{\pi \mu' n^2}{\ell} (b^2 - a^2) - \frac{\mu 2\pi n^2}{\ell M_0(ka)} \frac{a}{k} M_1(ka) \sin\left(\theta_1(ka) - \theta_0(ka) - \frac{\pi}{4}\right) \quad (18)$$

The permeability of the different mediums used here, such as blood, salted water, gelatin, is practically identical to that of the glass. In this case, these variations can be considered negligible compared to other parameter as the conductivity. It follows then to consider that  $\mu \approx \mu' \approx \mu_0$ . Thus, the above equations can be written as follow:

$$R = R_0 - \frac{C_R L_0 2\omega}{ka} \frac{M_1(ka)}{M_0(ka)} \cos\left(\theta_1(ka) - \theta_0(ka) - \frac{\pi}{4}\right) \quad (19)$$

$$L = L_0 \left[ (1 - C_R) - \frac{2C_R}{ka} \frac{M_1(ka)}{M_0(ka)} \sin\left(\theta_1(ka) - \theta_0(ka) - \frac{\pi}{4}\right) \right] \quad (20)$$

where  $L_0$  is the inductance in vacuum,

$$L_0 = \frac{\pi \mu_0 b^2 n^2}{\ell} \quad (21)$$

$C_R$  is a factor. It corresponds to the ratio of the medium volume and the total volume inside the solenoid. It is defined by:

$$\frac{a^2}{b^2} = C_R \quad (22)$$

A simplified writing of the equations (19) and (20) gives the expressions of  $R$  and  $L$ :

$$R = R_0 + C_R L_0 \omega f_1(ka) \quad (23)$$

$$L = L_0 [(1 - C_R) + C_R f_2(ka)] \quad (24)$$

In our application the crucial parameter is the conductivity of our medium. Since measurements are carried out at fixed frequencies we consider all others parameters as constant, including the frequency. Taking into consideration that:

$$k = \sqrt{\sigma \mu \omega} = k' \sqrt{\sigma} \text{ with } k' = \sqrt{\omega \mu} . \quad (25)$$

The variable  $ka$  in the two above equations can be substituted by:  $K\sqrt{\sigma}$ , where

$$K = ak' . \quad (26)$$

We obtain the following equations as a final expression of  $R$  and  $L$  as follow:

$$R = R_0 + C_R L_0 \omega f_1(K\sqrt{\sigma}) \quad (27)$$

$$L = L_0 [(1 - C_R) + C_R f_2(K\sqrt{\sigma})] \quad (28)$$

The impedance  $Z$  is calculated as follow:

$$Z = R + jL\omega = R_0 + C_R L_0 \omega f_1(K\sqrt{\sigma}) + j\omega L_0 [(1 - C_R) + C_R f_2(K\sqrt{\sigma})] \quad (29)$$

In our application, the frequency, dimensions of the inductors, the permeability of the medium are constant while the conductivity is considered as the most important parameter. Consequently, the study of the impedance variation as a function of the conductivity requires the study of the two functions  $f_1(\sigma)$  and  $f_2(\sigma)$ .



$$f_1(\sigma) = -\frac{2}{K\sqrt{\sigma}} \frac{M_1(K\sqrt{\sigma})}{M_0(K\sqrt{\sigma})} \cos\left(\theta_1(K\sqrt{\sigma}) - \theta_0(K\sqrt{\sigma}) - \frac{\pi}{4}\right) \quad (30)$$

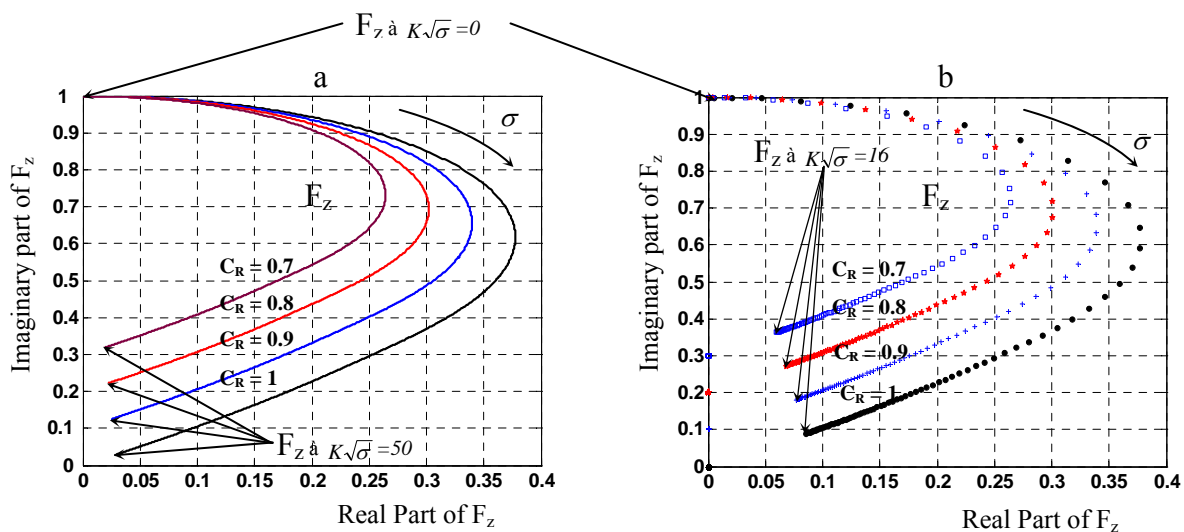
$$f_2(\sigma) = -\frac{2}{K\sqrt{\sigma}} \frac{M_1(K\sqrt{\sigma})}{M_0(K\sqrt{\sigma})} \sin\left(\theta_1(K\sqrt{\sigma}) - \theta_0(K\sqrt{\sigma}) - \frac{\pi}{4}\right) \quad (31)$$

### 2.4. Study of the Impedance Variation as Function of the Conductivity

The study of impedance  $Z$  is similar to the study of the following complex function:

$$F_z = C_R f_1(K\sqrt{\sigma}) + j \left[ (1 - C_R) + C_R f_2(K\sqrt{\sigma}) \right] \quad (32)$$

We have developed a Matlab<sup>®</sup> program to help illustrate the variation of  $F_z$  as a function of the conductivity. Fig. (5a and b) shows the evolution of the imaginary part of  $F_z$  versus reel part of  $F_z$  at different values of  $C_R$ . The curve (5a) is plotted in the interval of  $K\sqrt{\sigma}$  ranging from 0 to 50 with a step of 0.01, whereas the curve (5b) is plotted in a reduced interval ranging from 0 to 16, and with a step of 0.16. As it is demonstrated in the expression of the impedance, these curves represent the simultaneous variation of resistance  $R$  and inductance  $L$ . When the conductivity increases, we can observe two phases: an increase followed by decreases of the resistance  $R$  that corresponds to the real part of  $F_z$  and the inductance  $L$  corresponding to the imaginary part of  $F_z$ .



**Fig. 5.** Variation of  $F_z$  as a function of  $K\sqrt{\sigma}$  at different value of the factor  $C_R$ .

In Fig. (5b), the step of  $K\sqrt{\sigma}$  (0.16) used between two points being the same. The spaced points show that the function  $F_z$  and the impedance  $Z$  are very sensitive to the variation of conductivity in this region. When  $K\sqrt{\sigma}$  increases, the points become more close indicating that the reduction in the sensitivity of  $F_z$  and therefore  $Z$ , with respect to a variation of the medium conductivity. It is also important to observe that the spacing become larger when the load factor is high.

Thus, a sensor should have a better sensitivity to the variation of medium conductivity, when the load factor is close to 1.

### 2.4.1. Study of the Variation of the Resistance R and the Inductance L of the Inductor as a Function of Conductivity

Basing on numerical value of the elements of each inductors of our sensor, we plotted the variations of the resistance R and inductance L as a function of the conductivity as shown in Figs. 6 and 7 respectively. The expressions (3'') and (4'') show that we need to calculate all parameters. As a first step, we need to calculate the initial values of  $R_0$  and  $L_0$ .  $R_0$  and  $L_0$  do not represent the resistance and the inductance in continuous mode, but they represent the resistance and the inductance without the presence of the medium.

The capacity distributed of a solenoid results in an increase in its equivalent resistance  $R_0$ .

$$R_0 = \frac{R'_0}{\left[1 - \left(\frac{f}{f_0}\right)^2\right]^2} \quad [13] \quad (34)$$

Finally we obtain (see appendix for details):

$$R_0 = 1.02 * R'_0 = 7.5 \text{ ohm.}$$

Calculation of the inductance in vacuum  $L_0$ .

The inductance in vacuum of an inductor, taking into account of its capacity distributed, is given by the equation:

$$L_0 = \frac{l_0}{1 - \left(\frac{f}{f_0}\right)^2} \approx 1.015 * l_0 \approx 28.4 * 10^{-6} \text{H} \quad (35)$$

The aim of the calculation of all these parameters is to plot the curves, which give the variation of resistance R and inductance L of the sensor according to conductivity. These plots are obtained using a program developed under Matlab®.

### 2.4.2. Evolution of Resistance R as a Function of the Conductivity

Submitting all the parameters of the sensor by their calculated value in the equation (3'') given the expression of R, we obtain:

$$R = 7.5 + C_R 463 * f_i(K\sqrt{\sigma}) \quad (36)$$

Fig. 6 shows the evolution of the resistance R of our sensor as a function of the conductivity of the medium at different load factor  $C_R$  values. As indicated, for a medium with a high resistivity, the resistance R is equal to  $R_0$  (resistance at vacuum). At high load factor (close to 1), the resistance R increases to reach approximately 182.5 Ohm. This value is about 24 times its initial value for conductivity equal approximately to 0.185 S/m. As calculated, the variation of resistance is less important if the load factor is lower.

Beyond this value of the conductivity, when  $\sigma$  increases to infinite value or for a medium to very high conductivity, the resistance decreases to reach its initial value 7.5 ohm, at any value of the load factor. Overall, we can say that the higher is the load factor, the more sensitivity of the sensor to the conductivity is important.

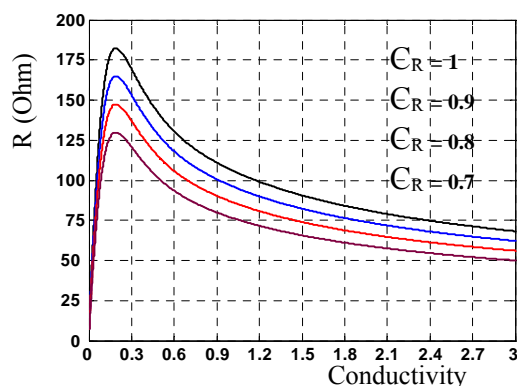


Fig. 6. Variation of the resistance as a function of the conductivity at various values of load factor.

### 2.4.3. Variation of Inductance L according to Conductivity

As is the case of the resistance R, submitting the elements of the sensor by their values, calculated before, we obtain the expression of L:

$$L = 28.4 * 10^{-6} [(1 - C_R) + C_R f_2(K\sqrt{\sigma})] \tag{37}$$

Fig. 7, demonstrates the variation of the inductance (L) versus conductivity of the medium at various values of the load factor  $C_R$ . In such medium with very high resistivity, the inductance is reaching its initial value at any value of the load factor  $C_R$ .

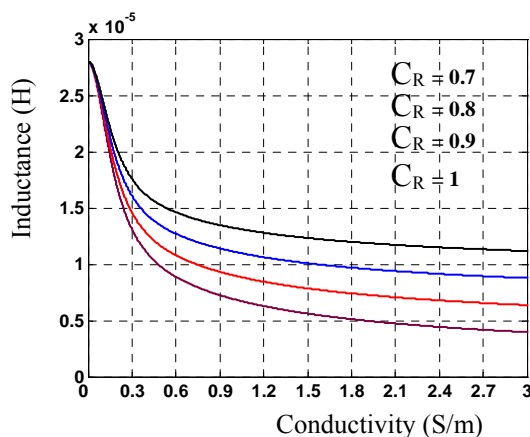


Fig. 7. Variation of the inductance (L) according to conductivity of the medium at various values of  $C_R$ .

### 2.5. Electric Model of the Sensor

The sensor consists of two inductors as shown in Fig. (8). A primary coil where, the alternate  $V_I$ , input signal provided by a function generator of output impedance 50 Ohm, is applied.

A second inductance through which we measured the output signal  $V_o$ . The sample under test represents the coupling that connects the two inductors. The self-capacitance of the inductor is about 1.5 pF. The self-resonance frequency of the inductor is then about 25 MHz. The resonance frequency of the sensor is between 2.5 MHz and 3MHz [12]. The schema of the electrical circuit of sensor is shown in Fig. 8.

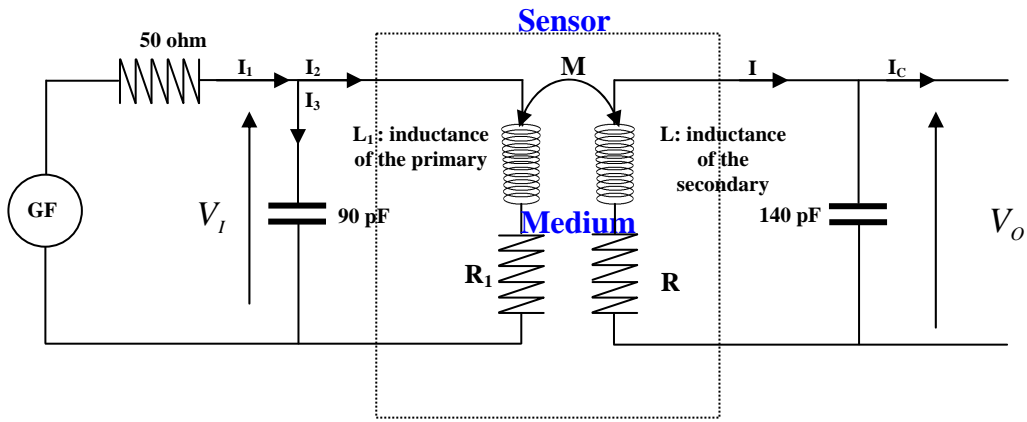


Fig. 8. Complete schema of the electrical circuit for measurement.

$R$ ,  $L$  and  $R_1$ ,  $L_1$  are the resistance and the inductance of the secondary and the primary coil of the sensor respectively. They are dependent on the medium conductivity. In this model, the variations of resistance and inductance of the two inductors are given by the following equations:

$$R = R_0 + C_R L_0 \omega f_1(K\sqrt{\sigma}) \quad (27)$$

$$R_1 = R_{01} + C_R L_{01} \omega f_1(K\sqrt{\sigma}) \quad (38)$$

$$L = L_0[(1 - C_R) + C_R f_2(K\sqrt{\sigma})] \quad (28)$$

$$L_1 = L_{01}[(1 - C_R) + C_R f_2(K\sqrt{\sigma})] \quad (39)$$

For flexibility, we chose to simulate the model using Matlab<sup>®</sup>. In this case, we calculate the mathematical formulas, which give the parameters to be simulated. Therefore, it is necessary to calculate the output signal  $V_o$ , the input signal  $V_I$ , the ratio  $V_o/V_I$ , and the impedance of the primary and secondary coil.

### 2.5.1. Calculation of the Output and Input Signal $V_o$ , $V_I$ , and $V_o/V_I$ according to the Parameters of the Circuit

From the circuit shown in Fig. 8, we have the following equations:

$$Z_1 I_2 + jM\omega\sqrt{L_1 L} I = \frac{E \sin(\omega t)}{jR_g C_1 \omega + 1} \quad (40)$$

and



$$Z I_1 + jM\omega\sqrt{L_1 L_2} I_2 = 0 \quad (41)$$

Where:

$$Z_1 = \left( R_1 + \frac{R_g}{1 + R_1^2 C_1^2 \omega^2} \right) + j \left( L_1 \omega - \frac{R_g^2 C_1 \omega}{1 + R_1^2 C_1^2 \omega^2} \right) \quad (42)$$

$$Z = R + j \left( L \omega - \frac{1}{C \omega} \right) \quad (43)$$

With  $I_C = 0$ , we obtain the formula which gives the output signal  $V_o$  :

$$V_o = - \frac{j \omega M \sqrt{L L_1} \text{Esin}(\omega t)}{(j R_g C_1 \omega + 1)(Z Z_1 + M^2 L L_1 \omega^2)} * \frac{1}{j C \omega} \quad (44)$$

The input signal  $V_I$  is expressed as:

$$V_I = \frac{\left( (\omega M \sqrt{L L_1})^2 + Z^* (R_1 + L_1 \omega) \right) \text{Esin}(\omega t)}{(j R_g C_1 \omega + 1)(Z Z_1 + M^2 L L_1 \omega^2)} \quad (45)$$

The ratio  $V_o/V_I$  is then expressed as:

$$V_o/V_I = - \frac{M \sqrt{L L_1}}{C \left( (\omega M \sqrt{L L_1})^2 + Z^* (R_1 + L_1 \omega) \right)} \quad (46)$$

with M: the mutual inductance; other symbols have been identified.

The impedance Z will be substituted by the values of R, L,  $R_1$ ,  $L_1$  given previously in its expression, and the functions  $f_1$ ,  $f_2$  take the same expression respectively. As it can be seen, the ratio  $V_o/V_I$  is independent of the amplitude of the input signal. The study and the simulation of these equations were carried out using a program developed under Matlab<sup>®</sup> software. The curves are plotted as a function of the frequency and of the conductivity  $\sigma$ . The amplitude of the input signal used in these simulations is of 12 Volts.

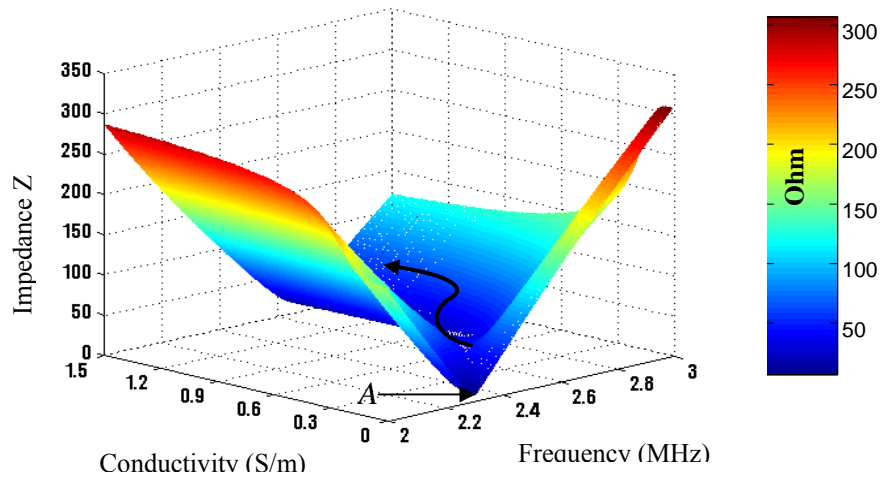
### 3. Results and Discussion

#### 3.1. Simulation of the Impedance Z Variation

Fig. 9 shows the simultaneous variation of the impedance Z of the secondary coil as a function of frequency and the conductivity of the medium, especially, at its minimum point.

At a frequency equal to 2.325 MHz and for conductivity practically null, the curve shows well that impedance Z reached its minimal value (denoted point A). When conductivity increases, this minimum point shifts towards the left at a higher frequency as the arrow indicates it. In addition, when the conductivity of the medium increases, the impedance Z of the minimum (point A) of the curve also increases until reaching a value equal to 48.7 ohm for a conductivity which closes to approximately

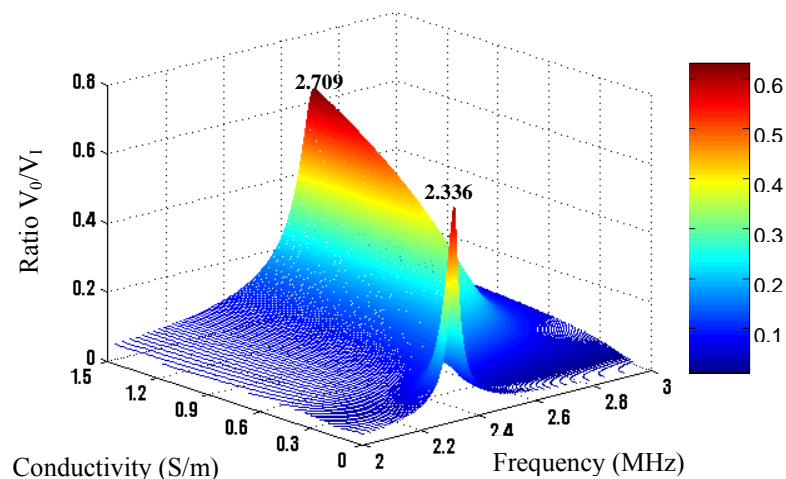
0.24. When the conductivity is higher than 0.24 the impedance  $Z$  decreases. The impedance  $Z$  shows sensitivity to the variation of conductivity



**Fig. 9.** Simultaneous variation of the impedance  $Z$  of the secondary coil in the frequency range (2-3MHz) and the conductivity of the medium.

### 3.2. Simulation of the Variation of the Amplitude of the Ratio $V_o/V_i$

Fig. 10 illustrates the 3D representation of the amplitude variation of the ratio of the output signal  $V_o$  and the input signal as a function of frequency and of conductivity of the medium. The curve shows that the resonance frequency shifts towards the left when conductivity increases. That is due to the decrease in inductance when the conductivity increases, as it was illustrated on Fig. (7). We can also observe that the amplitude of the ratio  $V_o/V_i$  shows two phases: The amplitude quickly decreases to increase afterward when the conductivity continues to increase more.



**Fig. 10.** Evolution of the ratio of the amplitude in the frequency (2-3MHz) and according of the conductivity of the medium.

This variation of amplitude is due basically to the direct variation of the function  $F_Z(K\sqrt{\sigma})$ , as it was shown before on Fig. (5). At the resonance frequency (2.324 MHz) the ratio reaches 0.619 for a medium, where the conductivity is practically zero. The amplitude decreases quickly to reach a value of 0.135 during the transition from an insulating medium to a slightly conducting medium. In contrast, the amplitude of the ratio increases to reach a value of 0.638 at a frequency of 2.716 MHz. The curve shows a shift of the resonance frequency when the conductivity increases.

The sensitivity of the ratio  $V_o/V_I$  to the variation of the conductivity of the medium is higher at the resonance frequency. This sensitivity to the variation of conductivity is very important than that of the output signal  $V_o$  (this study will be presented later). For example, at the resonance frequency, the amplitude ratio between a medium of conductivity 1.5 S/m and another of 0.75 S/m, the ratio of the output signals  $V_o$  (1.5 S/m)/  $V_o$  (0.75 S/m) gives 1.56, whereas the ratio  $V_o/V_I$  (1.5 S/m)/  $V_o/V_I$  (0.75 S/m) gives 1.64. In other words, the change of conductivity from 0.75 to 1.5 the output voltage increases by 56 %, while the ratio  $V_o/V_I$  increases by 64%.

The shift of the resonance frequency as shown in these curves is mainly due to the variation of the inductance (L) of the inductors as it was shown on Fig. 7. While the variations of amplitude at the same time is due to the variation of the resistance R of the inductors and to the variation of its inductance, as it was illustrated on Fig. 6 and Fig. 7 respectively, or quite simply with the variation of function  $F_Z(K\sqrt{\sigma})$  as it was shown on Fig. 5.

#### 4. Conclusion

In this work, we studied a model of the non-invasive sensor for the measurement of glycaemia. This model is based on the calculation of the expression of the flux through each inductor of the sensor. Contrary to an insulating medium, we demonstrated that the flux is a complex quantity in a conducting medium, The inductors are considered as a long solenoid, which is the case of the inductors that constitute our sensor. In order to analyze the complex equations included in our model, we have developed a Matlab<sup>®</sup> program. This program also allows studying the influence of the various parameters such as radius of inductors, frequency, factor of filling. Using a simple modification to the program, we have examined whether an increase in the radius of the inductance could improve the sensitivity of the sensor. Results from different curves are plotted indicating the variation of the various signals according to the conductivity of the medium under test. All magnitudes of  $V_o$ ,  $V_I$  and  $V_o/V_I$  showed an important sensitivity to the variation of conductivity. The ratio  $V_o/V_I$  combines the sensitivity of  $V_o$  and of  $V_I$ . These simulation data requires further examination under experimental measurements [14, 15].

#### Appendix

The capacity distributed of a solenoid results in an increase in its equivalent resistance  $R_o$ .

$$R_o = \frac{R'_o}{\left[1 - \left(\frac{f}{f_0}\right)^2\right]^2} \quad [13] \quad (A1)$$

It is necessary to calculate the resistance  $R'_0$  first of all, which represents the resistance of the inductor without its capacitance, and its-self frequency  $f_0$  of this inductor. We use the relation [13]:

$$\frac{R'_0}{r_0} = \frac{r}{2\delta} K(r/s, \ell/D) \quad (A2)$$

$K(r/s, \ell/D)$  represents a correction function due to the proximity effect on the resistance of the coil at high frequency.

Where:

$r_0$  is the resistance in continuous mode and it is given by:

$$r_0 = \frac{\rho l}{s} \approx 0.33 \text{ ohm.} \quad (A3)$$

$r$  represents the radius of the wire, which is equal to 0.5 mm.

$\ell$ ,  $s$ ,  $\rho$ ,  $D$  are the length, the section, the resistivity and the diameter respectively of the coil.

The penetration depth is calculated by the relation:

$$\delta = \frac{\sqrt{2}}{\sqrt{\mu_{cu} \sigma_{cu} \omega}} = 4 * 10^{-5} \text{ m} \quad (A4)$$

This value is calculated at fixed frequency ( $F= 2.6$  MHz).  $\mu_{cu}$ ,  $\sigma_{cu}$  are the permeability and the conductivity of the copper wire, respectively. The calculation of the function (Medhurst's theory)  $K(r/s, \ell/D)$  [13] equals to 3.5, when the length of the inductor is 80 mm, its diameter is 20 mm and that winding is tight. Then, we obtain the value of  $R'_0 = 7.3$  Ohm.

### **Calculation of $f_0$**

$f_0$  is defined by:

$$f_0 = \frac{1}{2\pi\sqrt{Cl_0}} \quad (A5)$$

where  $C$  is the distributed capacity  $C$  of the inductor,  $l_0$  is the inductance of the inductors without its self-capacitance  $C$ .

#### **a. Calculation of $C$**

For a solenoid with only one layer, the formula [13]

$$C = AD/10, \quad (A6)$$



is an approximation, which is often used in practice to evaluate this capacity.  $D$  is the diameter of the solenoid, and  $A$  is a coefficient that depends on the ratio of the length  $\ell$  of the solenoid to its diameter. The distributed capacity of this inductance is then:  $C \approx 1.5 \text{ pf}$ .

**b. Calculation of  $l_0$**

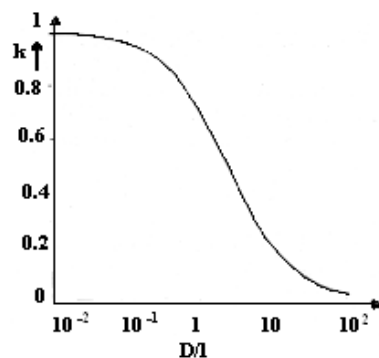
This result gives the inductance in vacuum of a solenoid without taking into account the effect of the distributed capacity  $C$ :

$$l_0 = K_c l'_0 \tag{A7}$$

With  $K_c$  is the Nagaoka's corrective factor [13] and  $l'_0$  is the inductance of the solenoid in vacuum. Considering it very long, and by neglecting the edge effect,  $l_0$  is given by:

$$l'_0 = N^2 \mu_0 \frac{D^2 \pi}{\ell} \approx 31.5 * 10^{-6} \text{ H}, \tag{A8}$$

where  $N$  is the number of whorls of the reel,  $\mu_0$  the permeability in vacuum,  $D$  and  $\ell$  are the diameter and the length of the inductor respectively. The length of our solenoid is four times larger than its diameter. Using Nagaoka's corrective factor of ( $K_c \approx 0.9$ ) then we obtained:  $l_0 \approx 28 * 10^{-6} \text{ H}$ . The value of Nagaoka's corrective factor  $K_c$  is obtained from the curve, Fig. A1, who traces this factor  $K_c$  according to the ratio  $D/\ell$  [13].



**Fig. A1.** The value of Nagaoka's corrective factor  $K_c$  for various values of the ratio  $D/\ell$ .

Thus that its-self resonance frequency of the inductor is:  $f_0 = \frac{1}{2\pi\sqrt{Cl_0}} \approx 2.5 * 10^7 \text{ Hz}$ . Since the maximum frequency of working band is 3 MHz, this gives a maximum ratio of:

$$\frac{f}{f_0} \approx 0.12. \text{ Finally we obtain: } R_0 = 1.02 * R'_0 = 7.5 \text{ ohm}.$$

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## Guide for Contributors

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### Aims and Scope

*Sensors & Transducers Journal* (ISSN 1726-5479) provides an advanced forum for the science and technology of physical, chemical sensors and biosensors. It publishes state-of-the-art reviews, regular research and application specific papers, short notes, letters to Editor and sensors related books reviews as well as academic, practical and commercial information of interest to its readership. Because of it is a peer reviewed international journal, papers rapidly published in *Sensors & Transducers Journal* will receive a very high publicity. The journal is published monthly as twelve issues per year by International Frequency Sensor Association (IFSA). In addition, some special sponsored and conference issues published annually. *Sensors & Transducers Journal* is indexed and abstracted very quickly by Chemical Abstracts, IndexCopernicus Journals Master List, Open J-Gate, Google Scholar, etc. Since 2011 the journal is covered and indexed (including a Scopus, Embase, Engineering Village and Reaxys) in Elsevier products.

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